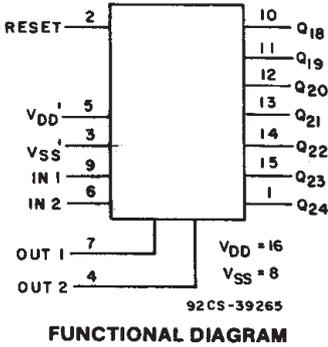


CD4521B Types

CMOS 24-Stage Frequency Divider

High-Voltage Types (20-Volt Rating)

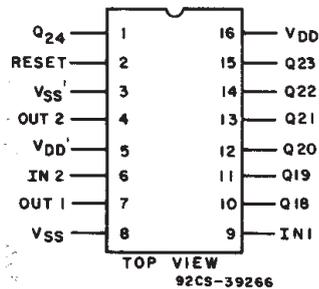


Features:

- Reset disables the RC oscillator for low-power standby condition
- V_{DD} and V_{SS} pins are brought out from the crystal oscillator to allow use of external resistors for low-power operation
- Maximum input current of 1 μ A at 18 V over full package-temperature range: 100 nA at 18 V and 25°C
- Common reset
- 100% tested for 20-V quiescent current
- 5, 10 and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Meets all requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

■ CD4521B consists of an oscillator section and 24 ripple-carry binary counter stages. The oscillator configuration (using IN1) allows design of either RC or crystal oscillator circuits. IN1 should be tied either HIGH or LOW when not in use. A HIGH on the RESET causes the counter to go to the all-0's state and disables the oscillator. The count is advanced on the negative transition of IN1 (and IN2). A time-saving test mode is described in the Functional Test Sequence Table and in Fig. 6.

The CD4521B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).



TERMINAL ASSIGNMENT

| OUTPUT | COUNT CAPACITY |
|--------|------------------------------|
| Q18 | 2 ¹⁸ = 262,144 |
| Q19 | 2 ¹⁹ = 524,288 |
| Q20 | 2 ²⁰ = 1,048,576 |
| Q21 | 2 ²¹ = 2,097,152 |
| Q22 | 2 ²² = 4,194,304 |
| Q23 | 2 ²³ = 8,388,608 |
| Q24 | 2 ²⁴ = 16,777,216 |

MAXIMUM RATINGS, Absolute-Maximum Values:

- DC SUPPLY-VOLTAGE RANGE, (V_{DD})
Voltages referenced to V_{SS} Terminal) -0.5V to +20V
- INPUT VOLTAGE RANGE, ALL INPUTS -0.5V to $V_{DD} + 0.5V$
- DC INPUT CURRENT, ANY ONE INPUT $\pm 10mA$
- POWER DISSIPATION PER PACKAGE (P_D):
For $T_A = -55^\circ C$ to $+100^\circ C$ 500mW
For $T_A = +100^\circ C$ to $+125^\circ C$ Derate Linearity at 12mW/ $^\circ C$ to 200mW
- DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR $T_A =$ FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
- OPERATING-TEMPERATURE RANGE (T_A) $-55^\circ C$ to $+125^\circ C$
- STORAGE TEMPERATURE RANGE (T_{stg}) $-65^\circ C$ to $+150^\circ C$
- LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s max $+265^\circ C$

CD4521B Types

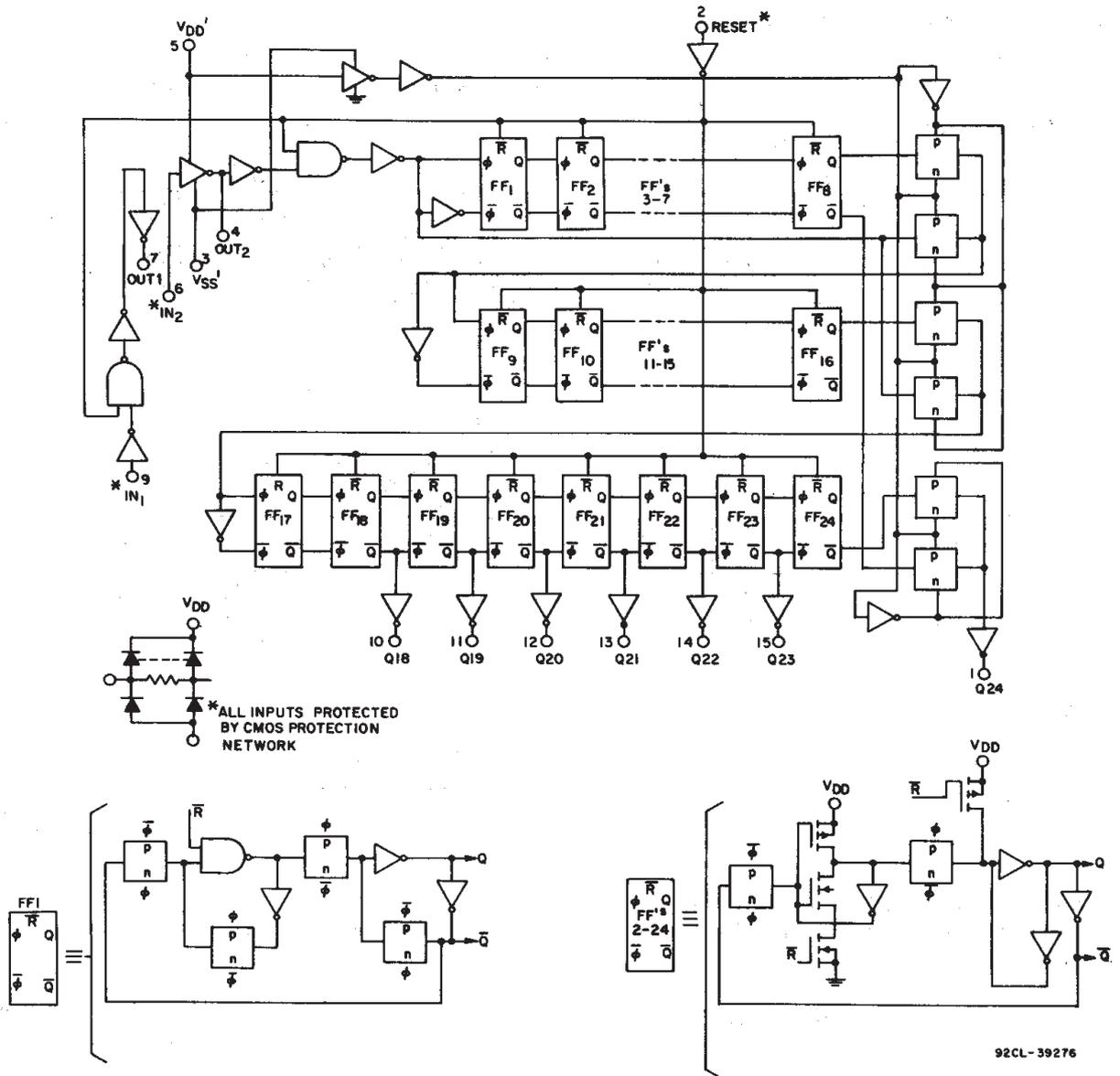


Fig. 1 - Logic diagram for CD4521B.

3
COMMERCIAL CMOS
HIGH VOLTAGE ICs

CD4521B Types

STATIC ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | CONDITIONS | | | LIMITS AT INDICATED TEMPERATURES (°C) | | | | | | | UNITS |
|--|-----------------------|------------------------|------------------------|---------------------------------------|-------|-------|-------|-------|-------------------|------|-------|
| | V _O (V) | V _{IN} (V) | V _{DD} (V) | -55 | -40 | +85 | +125 | +25 | | | |
| | | | | | | | | Min. | Typ. | Max. | |
| Quiescent Device Current, I _{DD} Max. | — | 0, 5 | 5 | 5 | 5 | 150 | 150 | — | 0.04 | 5 | μA |
| | — | 0, 10 | 10 | 10 | 10 | 300 | 300 | — | 0.04 | 10 | |
| | — | 0, 15 | 15 | 20 | 20 | 600 | 600 | — | 0.04 | 20 | |
| | — | 0, 20 | 20 | 100 | 100 | 3000 | 3000 | — | 0.08 | 100 | |
| Output Low (Sink) Current, I _{OL} Min. | 0.4 | 0, 5 | 5 | 0.64 | 0.61 | 0.42 | 0.36 | 0.51 | 1 | — | mA |
| | 0.5 | 0, 10 | 10 | 1.6 | 1.5 | 1.1 | 0.9 | 1.3 | 2.6 | — | |
| | 1.5 | 0, 15 | 15 | 4.2 | 4 | 2.8 | 2.4 | 3.4 | 6.8 | — | |
| Output High (Source) Current, I _{OH} Min. | 4.6 | 0, 5 | 5 | -0.64 | -0.61 | -0.42 | -0.36 | -0.51 | -1 | — | mA |
| | 2.5 | 0, 5 | 5 | -2 | -1.8 | -1.3 | -1.15 | -1.6 | -3.2 | — | |
| | 9.5 | 0, 10 | 10 | -1.6 | -1.5 | -1.1 | -0.9 | -1.3 | -2.6 | — | |
| | 13.5 | 0, 15 | 15 | -4.2 | -4 | -2.8 | -2.4 | -3.4 | -6.8 | — | |
| Output Voltage: Low-Level, V _{OL} Max. | — | 0, 5 | 5 | 0.05 | | | | — | 0 | 0.05 | V |
| | — | 0, 10 | 10 | 0.05 | | | | — | 0 | 0.05 | |
| | — | 0, 15 | 15 | 0.05 | | | | — | 0 | 0.05 | |
| Output Voltage: High-Level, V _{OH} Min. | — | 0, 5 | 5 | 4.95 | | | | 4.95 | 5 | — | V |
| | — | 0, 10 | 10 | 9.95 | | | | 9.95 | 10 | — | |
| | — | 0, 15 | 15 | 14.95 | | | | 14.95 | 15 | — | |
| Input Low Voltage, V _{IL} Max. | 0.5, 4.5 | — | 5 | 1.5 | | | | — | — | 1.5 | V |
| | 1, 9 | — | 10 | 3 | | | | — | — | 3 | |
| | 1.5, 13.5 | — | 15 | 4 | | | | — | — | 4 | |
| Input High Voltage, V _{IH} Min. | 0.5, 4.5 | — | 5 | 3.5 | | | | 3.5 | — | — | V |
| | 1, 9 | — | 10 | 7 | | | | 7 | — | — | |
| | 1.5, 13.5 | — | 15 | 11 | | | | 11 | — | — | |
| Input Current, I _{IN} Max. | — | 0, 18 | 18 | ±0.1 | ±0.1 | ±1 | ±1 | — | ±10 ⁻⁵ | ±0.1 | μA |

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operating is always within the following ranges:

| CHARACTERISTIC | V _{DD} (V) | LIMITS | | UNITS |
|--|------------------------|--------|------|-------|
| | | Min. | Max. | |
| Supply-Voltage Range (For T _A = Full Package-Temperature Range) | — | 3 | 18 | V |
| Input Pulse Width | 5 | 340 | — | ns |
| | 10 | 150 | — | |
| | 15 | 120 | — | |
| Reset Pulse Width | 5 | 180 | — | ns |
| | 10 | 80 | — | |
| | 15 | 50 | — | |
| Input Pulse Frequency | 5 | — | 2 | MHz |
| | 10 | — | 5 | |
| | 15 | — | 6.5 | |
| Input Pulse Rise or Fall Time | 5 | — | 15 | μs |
| | 10 | — | 15 | |
| | 15 | — | 15 | |
| R _T Operating Range | 5 | 1K | 10M | Ω |
| | 10 | 1K | 10M | |
| | 15 | 1K | 10M | |
| C _T Operating Range | 5 | 15p | 10M | F |
| | 10 | 15p | 10M | |
| | 15 | 15p | 10M | |

CD4521B Types

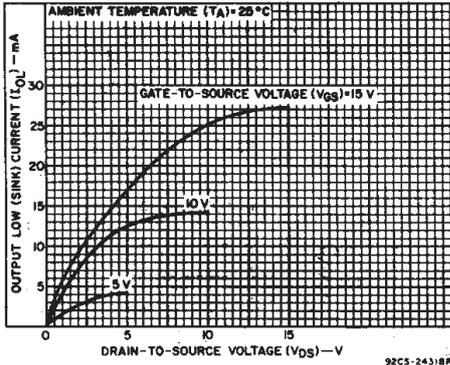


Fig. 2 - Typical output low (sink) current characteristics.

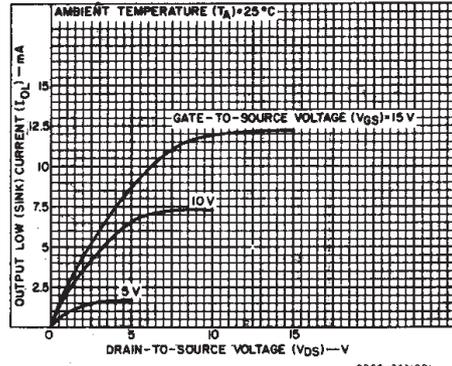


Fig. 3 - Minimum output low (sink) current characteristics.

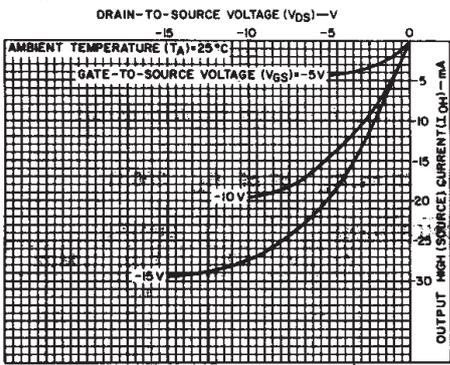


Fig. 4 - Typical output high (source) current characteristics.

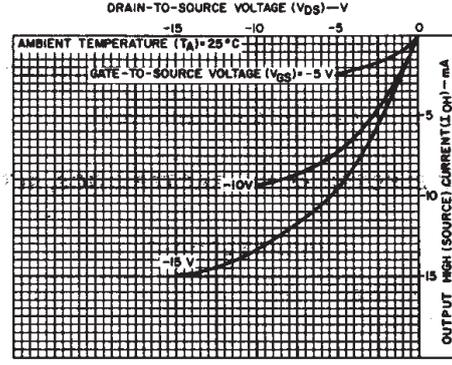


Fig. 5 - Minimum output high (source) current characteristics.

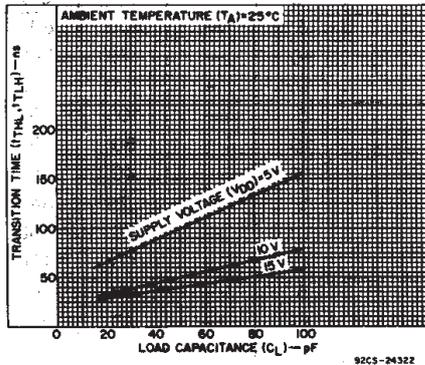


Fig. 6 - Typical transition time as a function of load capacitance.

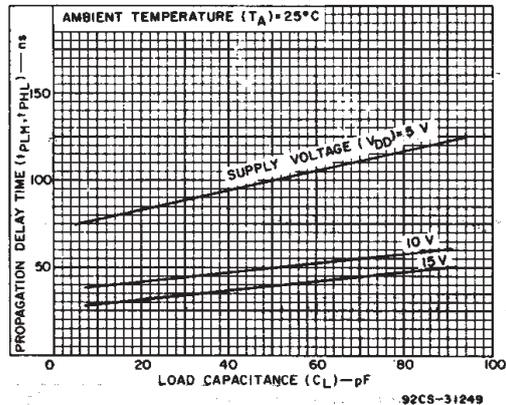


Fig. 7 - Typical propagation delay time (Q_n to $Q_n + 1$) as a function of load capacitance.

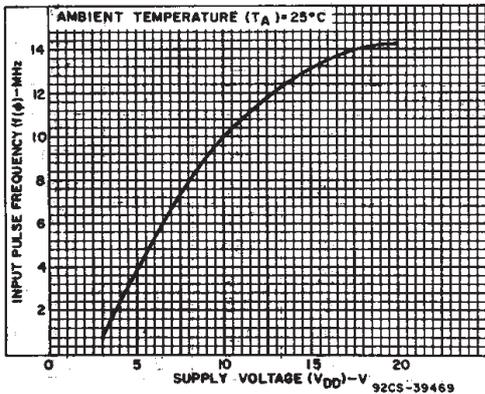


Fig. 8 - Typical maximum input pulse frequency vs. supply voltage.

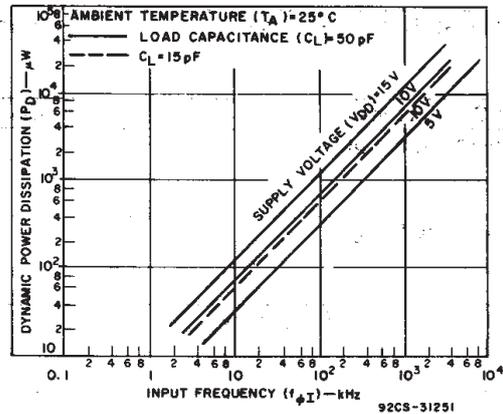


Fig. 9 - Typical dynamic power dissipation as a function of input frequency.

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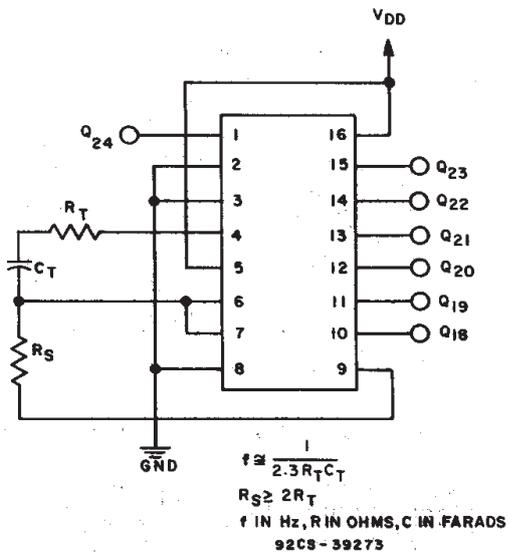


Fig. 10 - RC oscillator circuit.

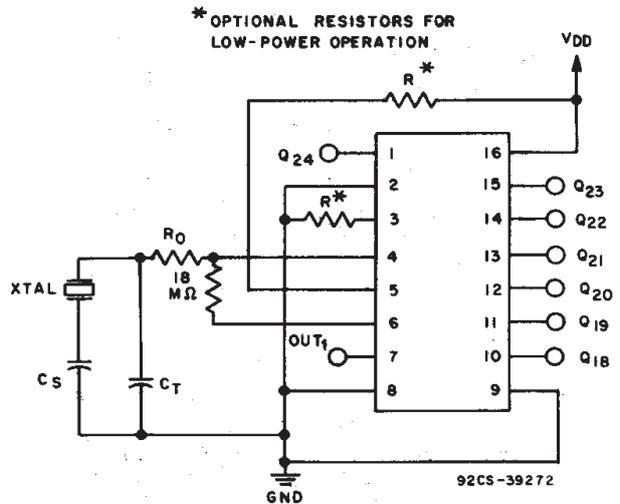


Fig. 11 - Crystal oscillator circuit.

DYNAMIC ELECTRICAL CHARACTERISTICS, At $T_A = 25^\circ\text{C}$; Input $t_r, t_f = 20\text{ ns}$, $C_L = 50\text{ pF}$, $R_L = 200\ \Omega$

| CHARACTERISTIC | TEST CONDITIONS | LIMITS | | | UNITS | |
|---|--|---------------------|------|------|----------|---------------|
| | | V _{DD} (V) | Min. | Typ. | | Max. |
| Propagation Delay Time: Input to Q18 | t_{PLH}, t_{PHL} | 5 | — | 4.5 | 9 | μs |
| | | 10 | — | 1.7 | 3.5 | |
| | | 15 | — | 1.3 | 2.7 | |
| Input to Q24 | | 5 | — | 6 | 12 | |
| | | 10 | — | 2.2 | 4.5 | |
| | | 15 | — | 1.7 | 3.5 | |
| Reset to Qn | | 5 | — | 400 | 800 | ns |
| | | 10 | — | 170 | 340 | |
| | | 15 | — | 120 | 240 | |
| Transition Time* | t_{THL}, t_{TLH} | 5 | — | 100 | 200 | |
| | | 10 | — | 50 | 100 | |
| | | 15 | — | 40 | 80 | |
| Minimum Input Pulse Width | $t_{w\phi}$ | 5 | — | 170 | 340 | |
| | | 10 | — | 75 | 150 | |
| | | 15 | — | 60 | 120 | |
| Minimum Reset Pulse Width | $t_{w(R)}$ | 5 | — | 90 | 180 | |
| | | 10 | — | 40 | 80 | |
| | | 15 | — | 25 | 50 | |
| Maximum Input Pulse Frequency | $f\phi$ | 5 | 2 | 4 | — | MHz |
| | | 10 | 5 | 10 | — | |
| | | 15 | 6.5 | 13 | — | |
| Input Pulse Rise or Fall Time | $t_r\phi, t_f\phi$ | 5 | — | — | 15 | μs |
| | | 10 | — | — | 15 | |
| | | 15 | — | — | 15 | |
| Input Capacitance | C_{IN} | Any Input | — | 5 | 7.5 | pF |
| R _T Operating Range | | 5 | 1K | — | 10M | Ω |
| | | 10 | 1K | — | 10M | |
| | | 15 | 1K | — | 10M | |
| C _T Operating Range | | 5 | 15p | — | 10 μ | F |
| | | 10 | 15p | — | 10 μ | |
| | | 15 | 15p | — | 10 μ | |
| Maximum Oscillator Frequency | R _T =1 K Ω C _T =15 pF R _S =30 K Ω | 5 | 0.5 | 0.7 | 0.9 | MHz |
| | | 10 | 1.2 | 1.5 | 1.8 | |
| | | 15 | 1.7 | 2.1 | 2.5 | |

*Not applicable for pin 4 (OUT2).

CD4521B Types

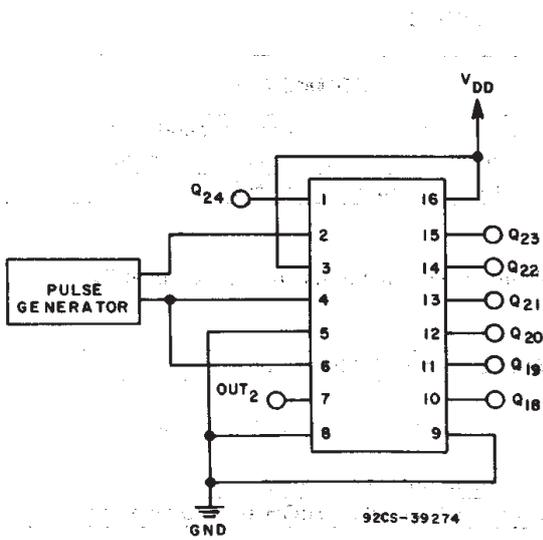


Fig. 12 - Functional test circuit.

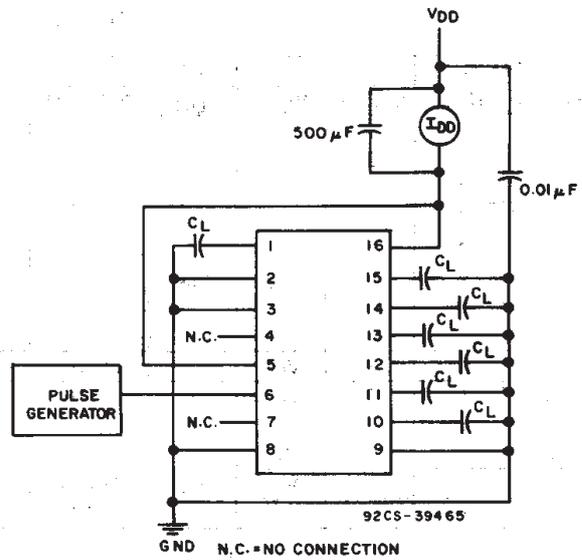


Fig. 13 - Dynamic power dissipation test circuit.

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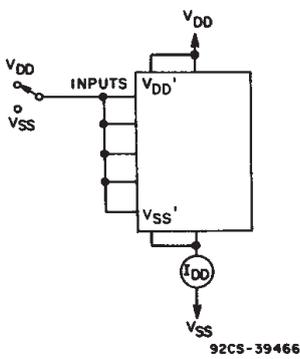


Fig. 14 - Quiescent device current.

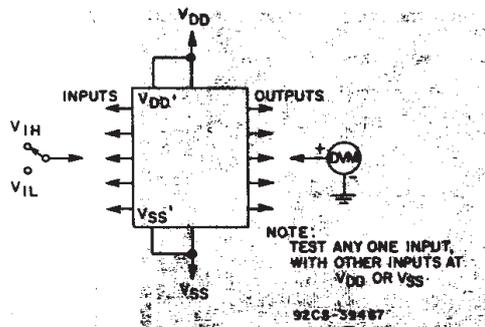


Fig. 15 - Input voltage.

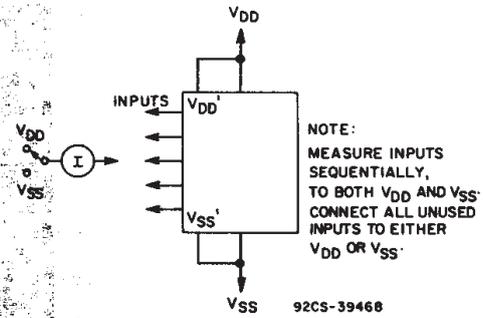


Fig. 16 - Input current.

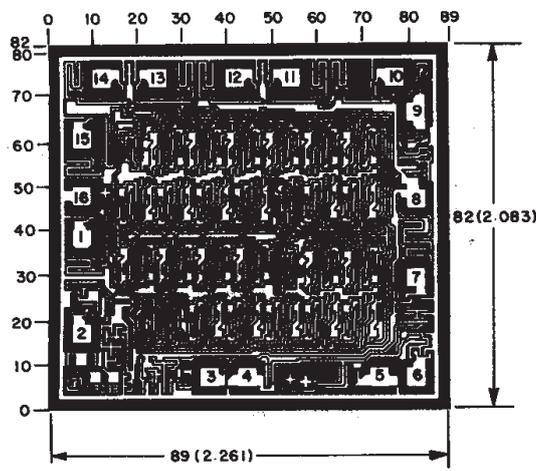
CD4521B Types

FUNCTIONAL TEST SEQUENCE

| INPUTS | | OUTPUTS | | | | COMMENTS |
|--------|------|---------|-------------------|-------------------|---------|---|
| RESET | IN 2 | OUT 2 | V _{SS} ' | V _{DD} ' | Q18-Q24 | |
| 1 | 0 | 0 | V _{DD} | V _{SS} | LOW | Counter is in three 8-stage sections in parallel mode. Counter is reset. IN 2 and OUT 2 are tied together. |
| 0 | 1 | 1 | V _{DD} | V _{SS} | | First LOW-to-HIGH transition at IN 2. |
| 0 | 0 | 0 | V _{DD} | V _{SS} | | 255 LOW-to-HIGH transitions are clocked in at IN 2. |
| | 1 | 1 | | | | |
| | — | — | | | | |
| | — | — | | | | |
| 0 | 1 | 1 | V _{DD} | V _{SS} | HIGH | The 255th LOW-to-HIGH transition. |
| 0 | 0 | 0 | V _{DD} | V _{SS} | HIGH | Counter is converted back to 24-stage serial-mode operation. |
| 0 | 0 | 0 | V _{SS} | V _{SS} | HIGH | |
| 0 | 1 | 0 | V _{SS} | V _{DD} | HIGH | |
| 0 | 1 | | V _{SS} | V _{DD} | HIGH | |
| 0 | 0 | | V _{SS} | V _{DD} | LOW | Counter ripples from an all-HIGH state to an all-LOW state. |

A test function, which divides, has been included to reduce the time required to test all 24 stages of the counter. Three sections are loaded in parallel to 255 counts, forcing all the outputs to be in the HIGH state. The counter is changed

back to serial-mode operation and one additional LOW-to-HIGH transition is entered at IN 2, which causes the outputs to ripple from an all-HIGH state to an all-LOW state.



92CS-39275
Dimensions and pad layout for CD4521BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

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